### 1 Features
- Dual-H-Bridge Motor Driver
  - Capable of Driving Two DC Motors or One Stepper Motor
  - Low-MOSFET ON-Resistance: \( \text{HS + LS} \approx 305 \, \text{m}\Omega \)
- 1.5-A Maximum Drive Current Per H-Bridge
- Configure Bridges Parallel for 3-A Drive Current
- Separate Motor and Logic-Supply Pins:
  - 0-V to 11-V Motor-Operating Supply-Voltage
  - 2-V to 7-V Logic Supply-Voltage
- Separate Logic and Motor Power Supply Pins
- Flexible PWM or PHASE/ENABLE Interface
- Low-Power Sleep Mode With 95-nA Maximum Supply Current
- Tiny 2.00-mm × 3.00-mm WSON Package

### 2 Applications
- Battery-Powered:
  - Cameras
  - DSLR Lenses
  - Consumer Products
  - Toys
  - Robotics
  - Medical Devices

### 3 Description
The DRV8835 provides an integrated motor driver solution for cameras, consumer products, toys, and other low-voltage or battery-powered motion control applications. The device has two H-bridge drivers, and drives two DC motors or one stepper motor, as well as other devices like solenoids. The output driver block for each consists of N-channel power MOSFETs configured as an H-bridge to drive the motor winding. An internal charge pump generates gate drive voltages.

The DRV8835 supplies up to 1.5-A of output current per H-bridge and operates on a motor power supply voltage from 0 V to 11 V, and a device power supply voltage of 2 V to 7 V.

PHASE/ENABLE and IN/IN interfaces are compatible with industry-standard devices.

Internal shutdown functions are provided for overcurrent protection, short circuit protection, undervoltage lockout, and overtemperature.

The DRV8835 is packaged in a tiny 12-pin WSON package (Eco-friendly: RoHS and no Sb/Br).

### Device Information

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>PACKAGE</th>
<th>BODY SIZE (NOM)</th>
</tr>
</thead>
<tbody>
<tr>
<td>DRV8835</td>
<td>WSON (12)</td>
<td>2.00 mm × 3.00 mm</td>
</tr>
</tbody>
</table>

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Simplified Schematic

```
Controller  PWM  DRV8835  Stepper or Brushed DC Motor Driver

VCC = 2 V to 7 V
VM = 0 V to 11 V
```

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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

### Changes from Revision F (April 2016) to Revision G  
**Page**

- Changed the **Layout Guidelines** to clarify the guidelines for the VM pin .......................................................... 14

### Changes from Revision E (December 2015) to Revision F  
**Page**

- Deleted nFAULT from the **Simplified Schematic** in the **Description** section .......................................................... 1

### Changes from Revision D (January 2014) to Revision E  
**Page**

- Added **ESD Ratings** table, **Feature Description** section, **Device Functional Modes**, **Application and Implementation** section, **Power Supply Recommendations** section, **Layout** section, **Device and Documentation Support** section, and **Mechanical, Packaging, and Orderable Information** section .......................................................... 1

### Changes from Revision C (September 2013) to Revision D  
**Page**

- Changed **Features** bullet .......................................................... 1
- Changed motor supply voltage range in **Description** section .......................................................... 1
- Changed Motor power supply voltage range in **Recommended Operating Conditions** .......................................................... 4
- Added $t_{OCR}$ and $t_{DEAD}$ parameters to **Electrical Characteristics** .......................................................... 5
- Added paragraph to **Power Supplies and Input Pins** section .......................................................... 13

---

2 Submit Documentation Feedback

Product Folder Links: **DRV8835**

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### Pin Configuration and Functions

#### DSS Package

<table>
<thead>
<tr>
<th>PIN</th>
<th>I/O(1)</th>
<th>DESCRIPTION</th>
<th>EXTERNAL COMPONENTS OR CONNECTIONS</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>POWER AND GROUND</strong></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>GND, Thermal pad</td>
<td>6</td>
<td>—</td>
<td>Device ground</td>
</tr>
<tr>
<td>VM</td>
<td>1</td>
<td>—</td>
<td>Motor supply</td>
</tr>
<tr>
<td>Bypass to GND with a 0.1-μF (minimum) ceramic capacitor</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>VCC</td>
<td>12</td>
<td>—</td>
<td>Device supply</td>
</tr>
<tr>
<td>Bypass to GND with a 0.1-μF (minimum) ceramic capacitor</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td><strong>CONTROL</strong></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>MODE</td>
<td>11</td>
<td>I</td>
<td>Input mode select</td>
</tr>
<tr>
<td>Logic low selects IN/IN mode</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Logic high selects PH/EN mode</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Internal pulldown resistor</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>AIN1/APHASE</td>
<td>10</td>
<td>I</td>
<td>Bridge A input 1/PHASE input</td>
</tr>
<tr>
<td>IN/IN mode: Logic high sets AOUT1 high</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>PH/EN mode: Sets direction of H-bridge A</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Internal pulldown resistor</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>AIN2/AENBL</td>
<td>9</td>
<td>I</td>
<td>Bridge A input 2/ENABLE input</td>
</tr>
<tr>
<td>IN/IN mode: Logic high sets AOUT2 high</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>PH/EN mode: Logic high enables H-bridge A</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Internal pulldown resistor</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>BIN1/BPHASE</td>
<td>8</td>
<td>I</td>
<td>Bridge B input 1/PHASE input</td>
</tr>
<tr>
<td>IN/IN mode: Logic high sets BOUT1 high</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>PH/EN mode: Sets direction of H-bridge B</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Internal pulldown resistor</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>BIN2/BENBL</td>
<td>7</td>
<td>I</td>
<td>Bridge B input 2/ENABLE input</td>
</tr>
<tr>
<td>IN/IN mode: Logic high sets BOUT2 high</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>PH/EN mode: Logic high enables H-bridge B</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Internal pulldown resistor</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td><strong>OUTPUT</strong></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>AOUT1</td>
<td>2</td>
<td>O</td>
<td>Bridge A output 1</td>
</tr>
<tr>
<td>AOUT2</td>
<td>3</td>
<td>O</td>
<td>Bridge A output 2</td>
</tr>
<tr>
<td>BOUT1</td>
<td>4</td>
<td>O</td>
<td>Bridge B output 1</td>
</tr>
<tr>
<td>Connect to motor winding B</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>BOUT2</td>
<td>5</td>
<td>O</td>
<td>Bridge B output 2</td>
</tr>
</tbody>
</table>

(1) Directions: I = input, O = output
6 Specifications

6.1 Absolute Maximum Ratings

<table>
<thead>
<tr>
<th></th>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Power supply voltage, VM</td>
<td>–0.3</td>
<td>12</td>
<td>V</td>
</tr>
<tr>
<td>Power supply voltage, VCC</td>
<td>–0.3</td>
<td>7</td>
<td>V</td>
</tr>
<tr>
<td>Digital input pin voltage</td>
<td>–0.5</td>
<td>VCC + 0.5</td>
<td>V</td>
</tr>
<tr>
<td>Peak motor drive output current</td>
<td>Internally limited</td>
<td>A</td>
<td></td>
</tr>
<tr>
<td>Continuous motor drive output current per H-bridge (3)</td>
<td>–1.5</td>
<td>1.5</td>
<td>A</td>
</tr>
<tr>
<td>T_J Operating junction temperature</td>
<td>–40</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>T_stg Storage temperature</td>
<td>–60</td>
<td>150</td>
<td>°C</td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

(3) Power dissipation and thermal limits must be observed.

6.2 ESD Ratings

<table>
<thead>
<tr>
<th>(ESD)</th>
<th>VALUE</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)</td>
<td>±2000</td>
<td>V</td>
</tr>
<tr>
<td>Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)</td>
<td>±1500</td>
<td>V</td>
</tr>
</tbody>
</table>

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

T_A = 25°C (unless otherwise noted)

<table>
<thead>
<tr>
<th></th>
<th>MIN</th>
<th>NOM</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_CC Device power supply voltage</td>
<td>2</td>
<td>7</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>V_M Motor power supply voltage</td>
<td>0</td>
<td>11</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>V_IN Logic level input voltage</td>
<td>0</td>
<td>V_CC</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>I_OUT H-bridge output current (1)</td>
<td>0</td>
<td>1.5</td>
<td>A</td>
<td></td>
</tr>
<tr>
<td>F_PWM Externally applied PWM frequency</td>
<td>0</td>
<td>250</td>
<td>kHz</td>
<td></td>
</tr>
</tbody>
</table>

(1) Power dissipation and thermal limits must be observed.

6.4 Thermal Information

<table>
<thead>
<tr>
<th>THERMAL METRIC (1)</th>
<th>DRV8835 DSS (WSON)</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>R_JA Junction-to-ambient thermal resistance</td>
<td>50.4</td>
<td>°C/W</td>
</tr>
<tr>
<td>R_JC(top) Junction-to-case (top) thermal resistance</td>
<td>58</td>
<td>°C/W</td>
</tr>
<tr>
<td>R_JB Junction-to-board thermal resistance</td>
<td>19.9</td>
<td>°C/W</td>
</tr>
<tr>
<td>Ψ_JT Junction-to-top characterization parameter</td>
<td>0.9</td>
<td>°C/W</td>
</tr>
<tr>
<td>Ψ_JB Junction-to-board characterization parameter</td>
<td>20</td>
<td>°C/W</td>
</tr>
<tr>
<td>R_JC(bot) Junction-to-case (bottom) thermal resistance</td>
<td>6.9</td>
<td>°C/W</td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.
### 6.5 Electrical Characteristics

\( T_A = 25^\circ C, \ V_M = 5 \ V, \ V_{CC} = 3 \ V \) (unless otherwise noted)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>POWER SUPPLY</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_{VM} )</td>
<td>VM operating supply current</td>
<td>85</td>
<td>200</td>
<td></td>
<td>( \mu A )</td>
</tr>
<tr>
<td></td>
<td>No PWM, no load</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>50 kHz PWM, no load</td>
<td>650</td>
<td>2000</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_{VMQ} )</td>
<td>VM sleep mode supply current</td>
<td>5</td>
<td></td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td></td>
<td>( V_M = 2 \ V, \ V_{CC} = 0 \ V, ) all inputs 0 V</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>( V_M = 5 \ V, \ V_{CC} = 0 \ V, ) all inputs 0 V</td>
<td>10</td>
<td>95</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_{VCC} )</td>
<td>VCC operating supply current</td>
<td>450</td>
<td>2000</td>
<td></td>
<td>( \mu A )</td>
</tr>
<tr>
<td><strong>LOGIC-LEVEL INPUTS</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( V_{IL} )</td>
<td>Input low voltage</td>
<td>0.3 \times V_{CC}</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>( V_{IH} )</td>
<td>Input high voltage</td>
<td>0.5 \times V_{CC}</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>( I_{IL} )</td>
<td>Input low current ( V_N = 0 )</td>
<td>–5</td>
<td>5</td>
<td></td>
<td>( \mu A )</td>
</tr>
<tr>
<td>( I_{IH} )</td>
<td>Input high current ( V_N = 3.3 \ V )</td>
<td>50</td>
<td></td>
<td></td>
<td>( \mu A )</td>
</tr>
<tr>
<td>( R_{PD} )</td>
<td>Pulldown resistance</td>
<td>100</td>
<td></td>
<td></td>
<td>k\Omega</td>
</tr>
<tr>
<td><strong>H-BRIDGE FETS</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( R_{DS(ON)} )</td>
<td>HS + LS FET on resistance</td>
<td>370</td>
<td>420</td>
<td></td>
<td>m\Omega</td>
</tr>
<tr>
<td></td>
<td>( V_{CC} = 3 \ V, \ V_M = 3 \ V, \ I_O = 800 \ mA, ) ( T_J = 25^\circ C )</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>( V_{CC} = 5 \ V, \ V_M = 5 \ V, \ I_O = 800 \ mA, ) ( T_J = 25^\circ C )</td>
<td>305</td>
<td>355</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_{OFF} )</td>
<td>OFF-state leakage current</td>
<td>±200</td>
<td></td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td><strong>PROTECTION CIRCUITS</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_{OCP} )</td>
<td>Overcurrent protection trip level</td>
<td>1.6</td>
<td>3.5</td>
<td></td>
<td>A</td>
</tr>
<tr>
<td>( t_{DEG} )</td>
<td>Overcurrent de-glitch time</td>
<td>1</td>
<td></td>
<td></td>
<td>( \mu s )</td>
</tr>
<tr>
<td>( t_{OCR} )</td>
<td>Overcurrent protection retry time</td>
<td>1</td>
<td></td>
<td></td>
<td>ms</td>
</tr>
<tr>
<td>( t_{DEAD} )</td>
<td>Output dead time</td>
<td>100</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>( t_{TSD} )</td>
<td>Thermal shutdown temperature</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
6.6 Timing Requirements

$T_A = 25^\circ C$, $V_M = 5$ V, $V_{CC} = 3$ V, $R_L = 20$ Ω

<table>
<thead>
<tr>
<th>NO.</th>
<th>Description</th>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>$t_1$ Delay time, xPHASE high to xOUT1 low</td>
<td>300</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>2</td>
<td>$t_2$ Delay time, xPHASE high to xOUT2 high</td>
<td>200</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>3</td>
<td>$t_3$ Delay time, xPHASE low to xOUT1 high</td>
<td>200</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>4</td>
<td>$t_4$ Delay time, xPHASE low to xOUT2 low</td>
<td>300</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>5</td>
<td>$t_5$ Delay time, xENBL high to xOUTx high</td>
<td>200</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>6</td>
<td>$t_6$ Delay time, xENBL high to xOUTx low</td>
<td>300</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>7</td>
<td>$t_7$ Output enable time</td>
<td>300</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>8</td>
<td>$t_8$ Output disable time</td>
<td>300</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>9</td>
<td>$t_9$ Delay time, xINx high to xOUTx high</td>
<td>160</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>10</td>
<td>$t_{10}$ Delay time, xINx low to xOUTx low</td>
<td>160</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>11</td>
<td>$t_{R}$ Output rise time</td>
<td>30</td>
<td>188</td>
<td>ns</td>
</tr>
<tr>
<td>12</td>
<td>$t_{F}$ Output fall time</td>
<td>30</td>
<td>188</td>
<td>ns</td>
</tr>
</tbody>
</table>

**Figure 1. Timing Requirements**
6.7 Typical Characteristics

Figure 2. VM Operating Current

Figure 3. Sleep Current

Figure 4. R_DS(ON) (High-Side + Low-Side)

Figure 5. V_CC Operating Current
7 Detailed Description

7.1 Overview

The DRV8835 is an integrated motor-driver solution used for brushed motor control. The device integrates two H-bridges, and drives two DC motor or one stepper motor. The output driver block for each H-bridge consists of N-channel power MOSFETs. An internal charge pump generates the gate drive voltages. Protection features include overcurrent protection, short circuit protection, undervoltage lockout, and overtemperature protection.

The bridges connect in parallel for additional current capability.

The DRV8835 allows separation of the motor voltage and logic voltage if desired. If VM and VCC are less than 7 V, the two voltages can be connected.

The mode pin allow selection of either a PHASE/ENABLE or IN/IN interface.

7.2 Functional Block Diagram
7.3 Feature Description

7.3.1 Protection Circuits
The DRV8835 is fully protected against undervoltage, overcurrent, and overtemperature events.

7.3.1.1 Overcurrent Protection (OCP)
An analog current limit circuit on each FET limits the current through the FET by removing the gate drive. If this analog current limit persists for longer than the OCP time, all FETs in the H-bridge disable. After approximately 1 ms, the bridge re-enable automatically.

Overcurrent conditions on both high-side and low-side devices; a short to ground, supply, or across the motor winding result in an overcurrent shutdown.

7.3.1.2 Thermal Shutdown (TSD)
If the die temperature exceeds safe limits, all FETs in the H-bridge disable. Operation automatically resumes once the die temperature falls to a safe level.

7.3.1.3 Undervoltage Lockout (UVLO)
If at any time the voltage on the VCC pins falls below the undervoltage lockout threshold voltage, all circuitry in the device disable, and internal logic resets. Operation resumes when VCC rises above the UVLO threshold.

<table>
<thead>
<tr>
<th>Table 1. Device Protection</th>
</tr>
</thead>
<tbody>
<tr>
<td>FAULT</td>
</tr>
<tr>
<td>VCC undervoltage (UVLO)</td>
</tr>
<tr>
<td>Overcurrent (OCP)</td>
</tr>
<tr>
<td>Thermal Shutdown (TSD)</td>
</tr>
</tbody>
</table>

7.4 Device Functional Modes
The DRV8835 is active when the VCC is set to a logic high. When in sleep mode, the H-bridge FETs are disabled (HIGH-Z).

<table>
<thead>
<tr>
<th>Table 2. Device Operating Modes</th>
</tr>
</thead>
<tbody>
<tr>
<td>OPERATING MODE</td>
</tr>
<tr>
<td>Operating</td>
</tr>
<tr>
<td>Sleep mode</td>
</tr>
<tr>
<td>Fault encountered</td>
</tr>
</tbody>
</table>
### 7.4.1 Bridge Control

Two control modes are available in the DRV8835: IN/IN mode, and PHASE/ENABLE mode. IN/IN mode is selected if the MODE pin is driven low or left unconnected; PHASE/ENABLE mode is selected if the MODE pin is driven to logic high. Table 3 and Table 4 show the logic for these modes.

<table>
<thead>
<tr>
<th>MODE</th>
<th>xIN1</th>
<th>xIN2</th>
<th>xOUT1</th>
<th>xOUT2</th>
<th>FUNCTION (DC MOTOR)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>0</td>
<td>0</td>
<td>Z</td>
<td>Z</td>
<td>Coast</td>
</tr>
<tr>
<td>0</td>
<td>0</td>
<td>1</td>
<td>L</td>
<td>H</td>
<td>Reverse</td>
</tr>
<tr>
<td>0</td>
<td>1</td>
<td>0</td>
<td>H</td>
<td>L</td>
<td>Forward</td>
</tr>
<tr>
<td>0</td>
<td>1</td>
<td>1</td>
<td>L</td>
<td>L</td>
<td>Brake</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th>MODE</th>
<th>xENABLE</th>
<th>xPHASE</th>
<th>xOUT1</th>
<th>xOUT2</th>
<th>FUNCTION (DC MOTOR)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>0</td>
<td>X</td>
<td>L</td>
<td>L</td>
<td>Brake</td>
</tr>
<tr>
<td>1</td>
<td>1</td>
<td>1</td>
<td>L</td>
<td>H</td>
<td>Reverse</td>
</tr>
<tr>
<td>1</td>
<td>1</td>
<td>0</td>
<td>H</td>
<td>L</td>
<td>Forward</td>
</tr>
</tbody>
</table>

### 7.4.2 Sleep Mode

If the VCC pin reaches 0 V, the DRV8835 enters a low-power sleep mode. In this state all unnecessary internal circuitry powers down. For minimum supply current, all inputs should be low (0 V) during sleep mode.
# Application and Implementation

## NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 8.1 Application Information

The DRV8835 is used in one or two motor control applications. Configure the DRV8835 in parallel to provide double the current to one motor. The following design procedure can be used to configure the DRV8835 in a brushed motor application.

## 8.2 Typical Application

The two H-bridges in the DRV8835 connect in parallel for double the current of a single H-bridge. Figure 6 shows the connections.

### 8.2.1 Design Requirements

Table 5 lists the design requirements.

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>REFERENCE</th>
<th>VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Motor voltage</td>
<td>VCC</td>
<td>4 V</td>
</tr>
<tr>
<td>Motor RMS current</td>
<td>I_{RMS}</td>
<td>0.3 A</td>
</tr>
<tr>
<td>Motor startup current</td>
<td>I_{START}</td>
<td>0.6 A</td>
</tr>
<tr>
<td>Motor current trip point</td>
<td>I_{LIMIT}</td>
<td>0.5 A</td>
</tr>
</tbody>
</table>

---

From Controller

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Figure 6. Parallel Mode Connections

---

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Table 5. Design Requirements

Product Folder Links: **DRV8835**
8.2.2 Detailed Design Procedure

8.2.2.1 Motor Voltage
The appropriate motor voltage depends on the ratings of the motor selected and the desired RPM. A higher voltage spins a brushed DC motor faster with the same PWM duty cycle applied to the power FETs. A higher voltage also increases the rate of current change through the inductive motor windings.

8.2.2.2 Lower-Power Operation
When entering sleep mode, TI recommends setting all inputs as a logic low to minimize system power.

8.2.3 Application Curve
The following scope captures motor startup as $V_{CC}$ ramps from 0 V to 6 V. Channel 1 is VCC, Channel 2 is VM, and Channel 4 is the motor current of an unloaded motor during startup. The motor used is a NMB Technologies Corporation, PPN7PA12C1. As VCC and VM ramp, the current in the motor increases until the motor speed builds up. The motor current then reduces for normal operation.

Inputs are set as follows:
- Mode: IN/IN
- AIN1: High
- AIN2: Low

![Motor Startup Scope](image)

**Figure 7. Motor Startup With No Load**
9 Power Supply Recommendations

9.1 Bulk Capacitance
The appropriate local bulk capacitance is an important factor in motor drive system design. More bulk capacitance is generally beneficial, but may increase costs and physical size.

The amount of local capacitance needed depends on a variety of factors, including:
• The highest current required by the motor system
• The power supply's capacitance and ability to source current
• The amount of parasitic inductance between the power supply and motor system
• The acceptable voltage ripple
• The type of motor used (brushed DC, brushless DC, stepper)
• The motor braking method

9.2 Power Supplies and Input Pins
There is a weak pulldown resistor (approximately 100 kΩ) to ground on the input pins.

VCC and VM may be applied and removed in any order. When VCC is removed, the device enters a low power state and draws very little current from VM. To minimize current draw, keep the input pins at 0 V during sleep mode.

The VM voltage supply does not have any undervoltage lockout protection (UVLO), so as long as VCC > 1.8 V, the internal device logic remains active. This means that the VM pin voltage may drop to 0 V, however, the load may not be sufficiently driven at low-VM voltages.
10 Layout

10.1 Layout Guidelines

The VCC pin should be bypassed to GND using low-ESR ceramic bypass capacitors with a recommended value of 0.1 \( \mu \text{F} \) rated for VCC. This capacitor should be placed as close to the VCC pin as possible with a thick trace.

The VM pin should be bypassed to GND using low-ESR ceramic bypass capacitors with a recommended value of 0.1 \( \mu \text{F} \) rated for VM. This capacitor should be placed as close to the VM pin as possible with a thick trace. The VM pin must bypass to ground using an appropriate bulk capacitor. This component can be an electrolytic and should be located close to the DRV8835.

10.2 Layout Example

![Layout Recommendation](image)

Figure 8. Layout Recommendation

10.3 Thermal Considerations

The DRV8835 has thermal shutdown (TSD) as described above. If the die temperature exceeds approximately 150°C, the device disables until the temperature drops to a safe level.

Any tendency of the device to enter thermal shutdown is an indication of either excessive power dissipation, insufficient heatsinking, or excessively high ambient temperature.

10.3.1 Power Dissipation

Power dissipation in the DRV8835 is dominated by the power dissipated in the output FET resistance, or \( R_{\text{DS(ON)}} \).

Average power dissipation when running both H-bridges can be roughly estimated by Equation 1:

\[
P_{\text{TOT}} = 2 \times R_{\text{DS(ON)}} \times (I_{\text{OUT(RMS)}})^2
\]

where

- \( P_{\text{TOT}} \) is the total power dissipation, \( R_{\text{DS(ON)}} \) is the resistance of the HS plus LS FETs, and \( I_{\text{OUT(RMS)}} \) is the RMS output current being applied to each winding. \( I_{\text{OUT(RMS)}} \) is equal to the approximately 0.7 \times the full-scale output current setting. The factor of 2 comes from the fact that there are two H-bridges.

The maximum amount of power dissipated in the device is dependent on ambient temperature and heatsinking.
Thermal Considerations (continued)

NOTE

$R_{DS(on)}$ increases with temperature, so as the device heats, the power dissipation increases. Consider this increase when sizing the heatsink.

The power dissipation of the DRV8835 is a function of RMS motor current and the resistance of each FET ($R_{DS(on)}$), see Equation 2.

$$\text{Power} = I_{\text{RMS}}^2 \times (\text{High-Side } R_{\text{DS(on)}} + \text{Low-Side } R_{\text{DS(on)}})$$

(2)

For this example, the ambient temperature is 35°C, and the junction temperature reaches 65°C. At 65°C, the sum of $R_{DS(on)}$ is about 1 Ω. With an example motor current of 0.8 A, the dissipated power in the form of heat will be $0.8 \, A^2 \times 1 \, \Omega = 0.64 \, W$.

The temperature that the DRV8835 reaches depends on the thermal resistance to the air and PCB. It is important to solder the device PowerPAD to the PCB ground plane, with vias to the top and bottom board layers, in order dissipate heat into the PCB and reduce the device temperature. In the example used here, the DRV8835 had an effective thermal resistance $R_{\theta JA}$ of 47°C/W, and as shown in Equation 3.

$$T_j = T_A + (R_{\theta} \times R_{\theta JA}) = 35°C + (0.64 \, W \times 47°C/W) = 65°C$$

(3)

10.3.2 Heatsinking

The PowerPAD™ package uses an exposed pad to remove heat from the device. For proper operation, this pad must thermally connect to copper on the PCB to dissipate heat. On a multi-layer PCB with a ground plane, this can be accomplished by adding a number of vias to connect the thermal pad to the ground plane. On PCBs without internal planes, copper area can be added on either side of the PCB to dissipate heat. If the copper area is on the opposite side of the PCB from the device, thermal vias are used to transfer the heat between top and bottom layers.

For more PCB design details, refer to PowerPAD™ Thermally Enhanced Package (SLMA002) and PowerPAD™ Made Easy (SLMA004), available at www.ti.com.

In general, the more copper area that is provided, the more power can be dissipated.
11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation
For related documentation see the following:
• Calculating Motor Driver Power Dissipation, SLVA504
• DRV8835/DRV8836 Evaluation Module, SLVU694
• Understanding Motor Driver Current Ratings, SLVA505

11.2 Community Resources
The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community  TI’s Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support  TI’s Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks
PowerPAD, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary
SLYZ022 — TI Glossary.
This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
## PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan</th>
<th>Lead/Ball Finish</th>
<th>MSL Peak Temp</th>
<th>Op Temp (°C)</th>
<th>Device Marking</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>DRV8835DSSR</td>
<td>ACTIVE</td>
<td>WSON</td>
<td>DSS</td>
<td>12</td>
<td>3000</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-2-260C-1 YEAR</td>
<td>-40 to 85</td>
<td>835</td>
<td></td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:

**ACTIVE**: Product device recommended for new designs.

**LIFEBUY**: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE**: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check [http://www.ti.com/productcontent](http://www.ti.com/productcontent) for the latest availability information and additional product content details.

**Pb-Free (RoHS)**: TI’s terms “Lead-Free” or “Pb-Free” mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt)**: This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br)**: TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material).

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

### TAPE DIMENSIONS

- **K0**: Dimension designed to accommodate the component width
- **B0**: Dimension designed to accommodate the component length
- **A0**: Dimension designed to accommodate the component thickness
- **W**: Overall width of the carrier tape
- **P1**: Pitch between successive cavity centers

### REEL DIMENSIONS

- **Reel Diameter**: Diameter of the reel
- **Reel Width (W1)**: Width of the reel

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

- **Q1**: Quadrant 1
- **Q2**: Quadrant 2
- **Q3**: Quadrant 3
- **Q4**: Quadrant 4

*All dimensions are nominal.*

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
<th>Pin 1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>DRV8835DSSR</td>
<td>WSON</td>
<td>DSS</td>
<td>12</td>
<td>3000</td>
<td>180.0</td>
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<td>1.05</td>
<td>4.0</td>
<td>8.0</td>
<td>Q1</td>
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<tr>
<td>Device</td>
<td>Package Type</td>
<td>Package Drawing</td>
<td>Pins</td>
<td>SPQ</td>
<td>Length (mm)</td>
<td>Width (mm)</td>
<td>Height (mm)</td>
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<td>DRV8835DSSR</td>
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<td>210.0</td>
<td>185.0</td>
<td>35.0</td>
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</tr>
</tbody>
</table>

*All dimensions are nominal*
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. SOT (Small Outline No-Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.

www.ti.com
THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

![Exposed Thermal Pad Dimensions Diagram]

NOTE: All linear dimensions are in millimeters.
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC-7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com (<http://www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for solder mask tolerances.
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